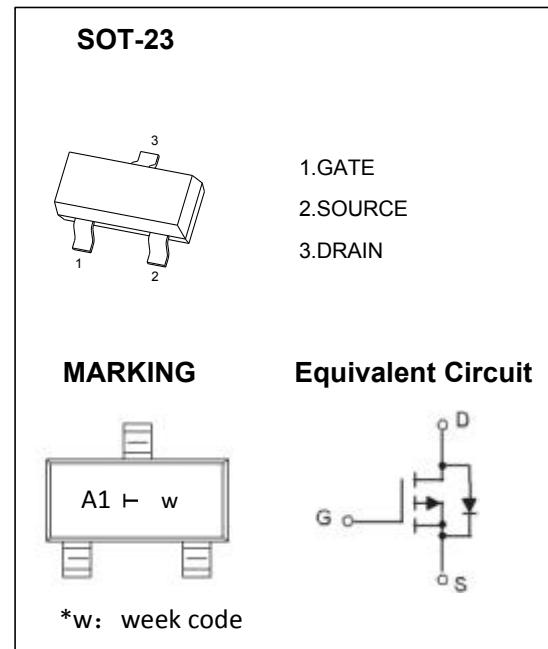


SOT-23 Plastic-Encapsulate MOSFETS

TF2301A

TF2301A P-Channel 20-V(D-S) MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}TYP$	I_D
-20V	0.055Ω@-4.5V	-3.0A
	0.075Ω@-2.5V	



General FEATURE

- TrenchFET Power MOSFET
- Lead free product is acquired
- Surface mount package

APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 12	
Continuous Drain Current	I_D	-3.0	A
Pulsed Drain Current	I_{DM}	-12	
Continuous Source-Drain Diode Current	I_S	-1.30	
Maximum Power Dissipation	P_D	1.25	W
Thermal Resistance from Junction to Ambient($t \leq 5s$)	$R_{\theta JA}$	165	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{stg}	-55 ~+150	

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MOSFET ELECTRICAL CHARACTERISTICS

T_a = 25 °C unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	-20			V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-0.5	-0.7	-1	
Gate-source leakage	I _{GSS}	V _{DS} = 0V, V _{GS} = ±8V			±100	nA
Zero gate voltage drain current	I _{bss}	V _{DS} = -20V, V _{GS} = 0V			-1	μA
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5V, I _D = -3.0A		0.055	0.075	Ω
		V _{GS} = -2.5V, I _D = -2.0A		0.075	0.090	
Forward transconductance ^a	g _f	V _{DS} = -5V, I _D = -2.0A	4.0	6.5		S
Dynamic^b						
Input capacitance	C _{iss}	V _{DS} = -10V, V _{GS} = 0V, f = 1MHz		585		pF
Output capacitance	C _{oss}			70		
Reverse transfer capacitance	C _{rss}			65		
Total gate charge	Q _g	V _{DS} = -10V, V _{GS} = -4.5V, I _D = -3A		5.5	10	nC
Gate-source charge	Q _{gs}	V _{DS} = -10V, V _{GS} = -2.5V, I _D = -2A		2.9	6	
Gate-drain charge	Q _{gd}			045		
Gate resistance	R _g			0.75		
Turn-on delay time	t _{d(on)}	V _{DD} = -10V, R _L = 5Ω, I _D = -1A, V _{GEN} = -4.5V, R _g = 3Ω		6.0		Ω
Rise time	t _r			9.8	20	ns
Turn-off delay time	t _{d(off)}			4.9	60	
Fall time	t _f			20.5	50	
				7.0	20	
Drain-source body diode characteristics						
Continuous source-drain diode current	I _s	T _c = 25°C			-1.3	A
Pulse diode forward current ^a	I _{SM}				-10	
Body diode voltage	V _{SD}	I _s = -1.0A		-0.8	-1.2	

Notes :

a. Pulse Test : Pulse Width < 300μs, Duty Cycle ≤ 2%.

b. Guaranteed by design, not subject to production testing.

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Typical Electrical and Thermal Characteristics

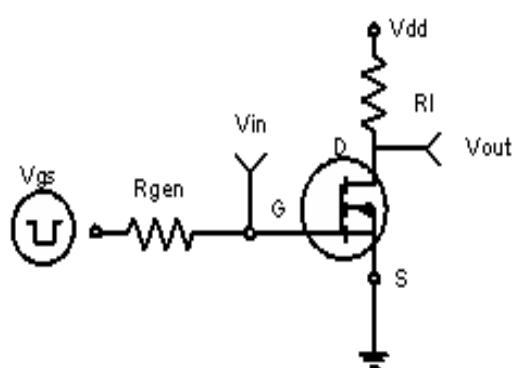


Figure 1:Switching Test Circuit

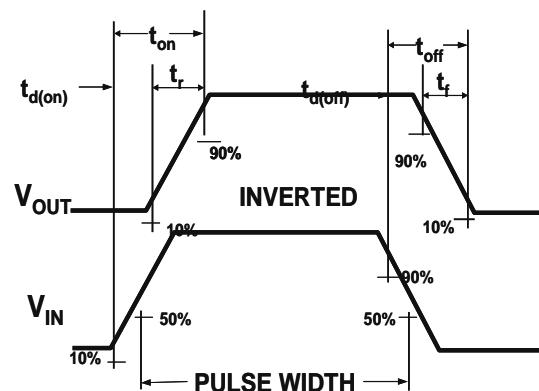


Figure 2:Switching Waveforms

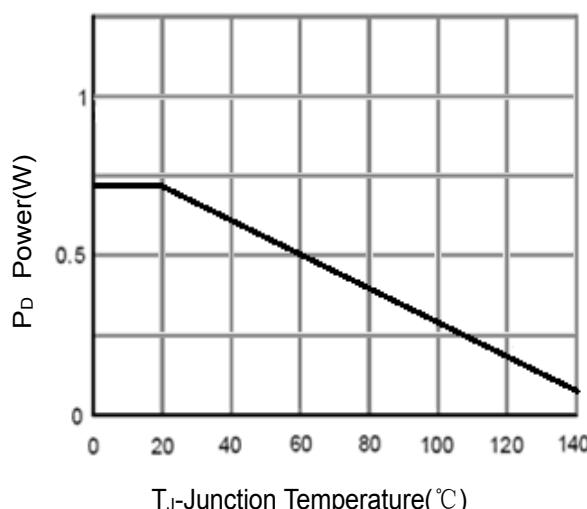
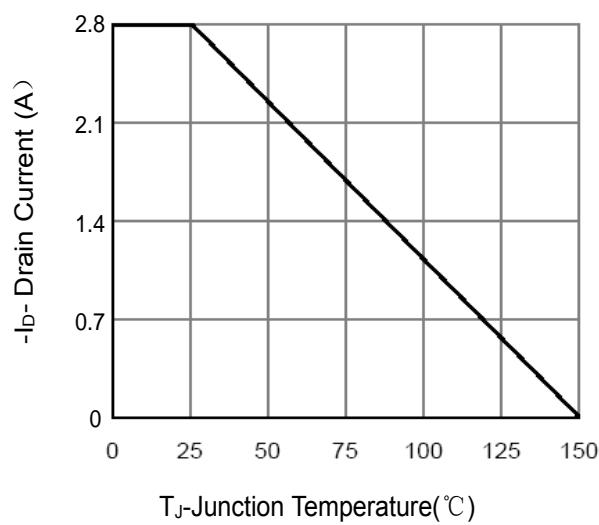


Figure 3 Power Dissipation



T_J-Junction Temperature(°C)

Figure 4 Drain Current

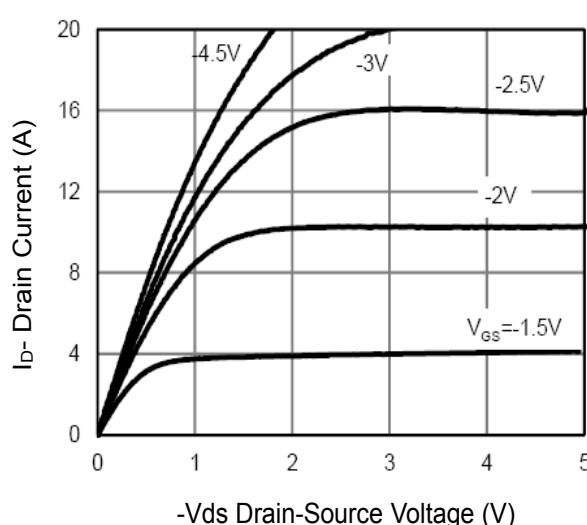


Figure 5 Output Characteristics

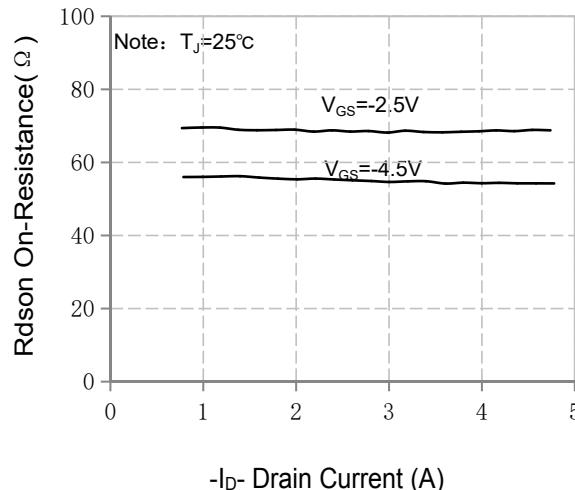


Figure 6 Drain-Source On-Resistance

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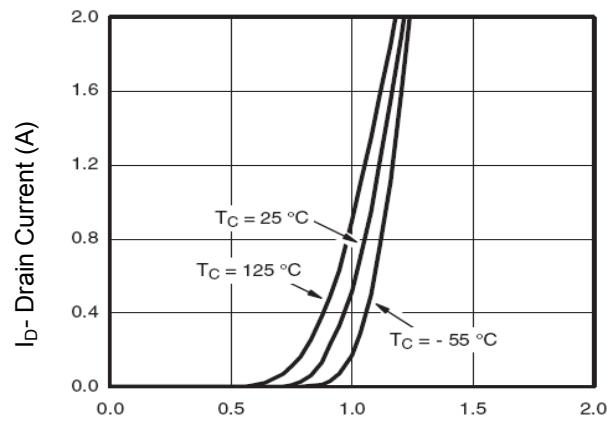


Figure 7 Transfer Characteristics

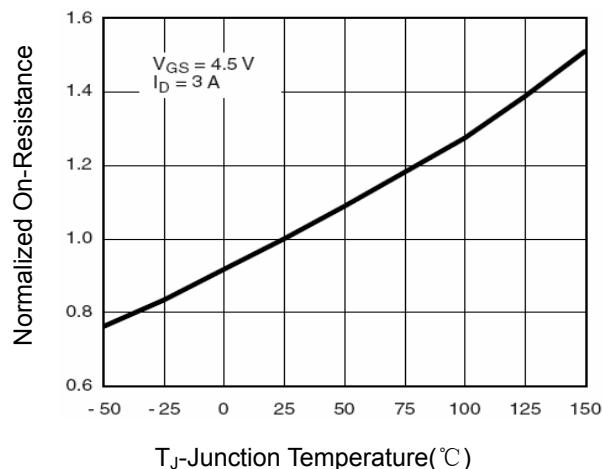


Figure 8 Drain-Source On-Resistance

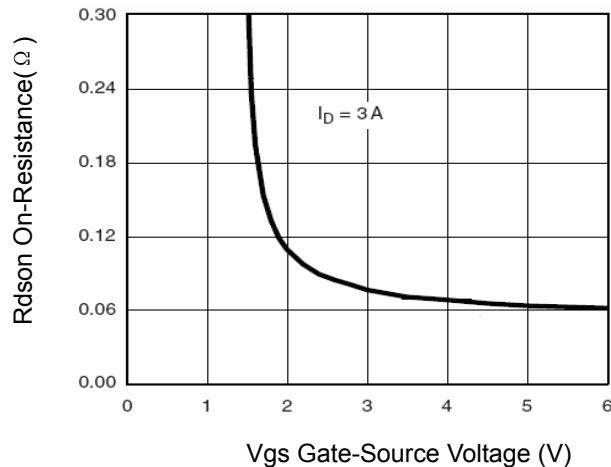


Figure 9 $R_{DS(on)}$ vs V_{GS}

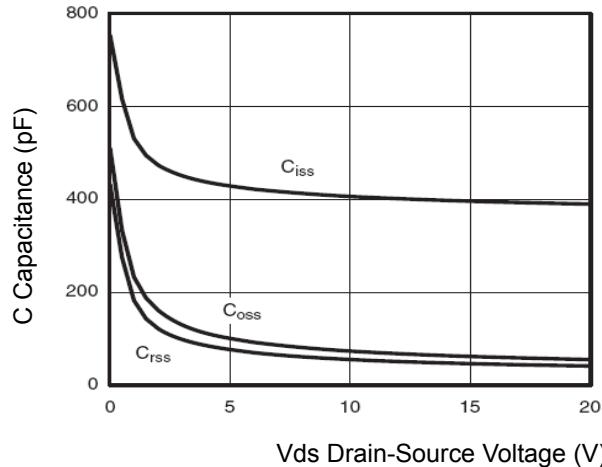


Figure 10 Capacitance vs V_{DS}

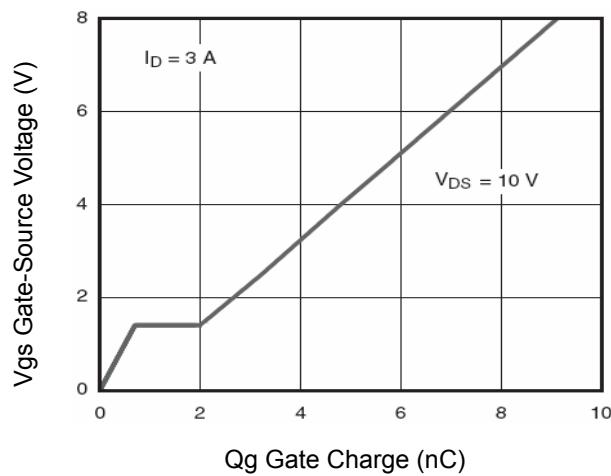


Figure 11 Gate Charge

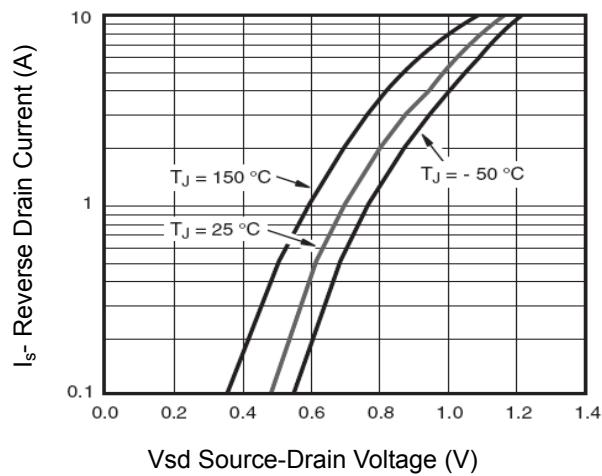


Figure 12 Source-Drain Diode Forward

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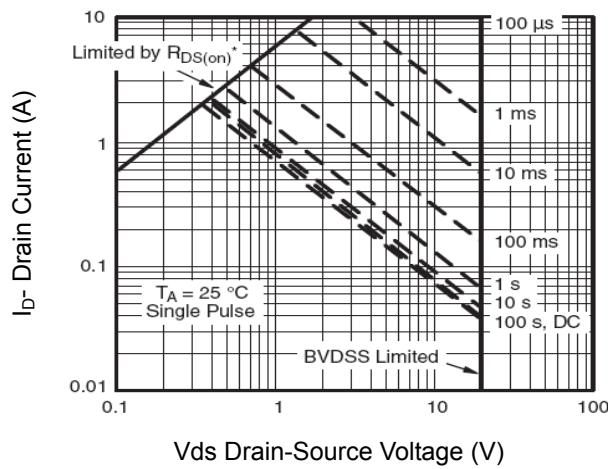


Figure 13 Safe Operation Area

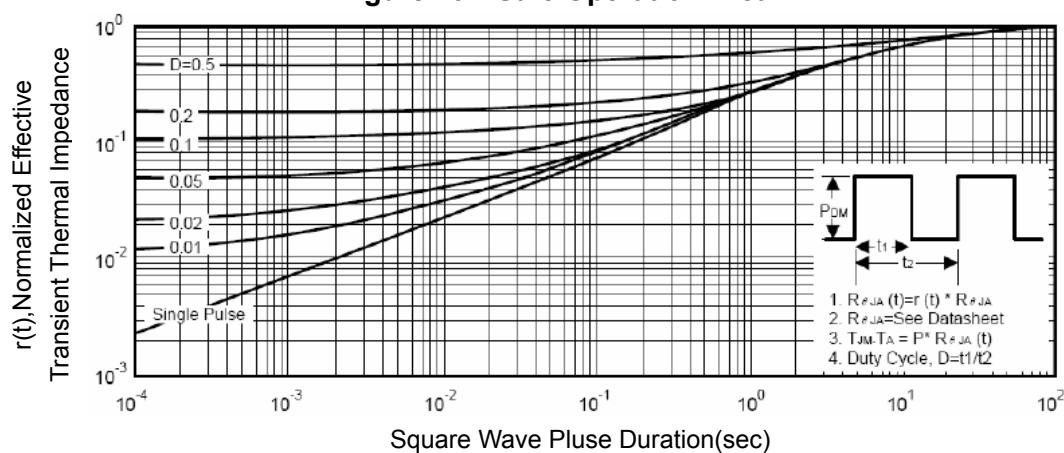


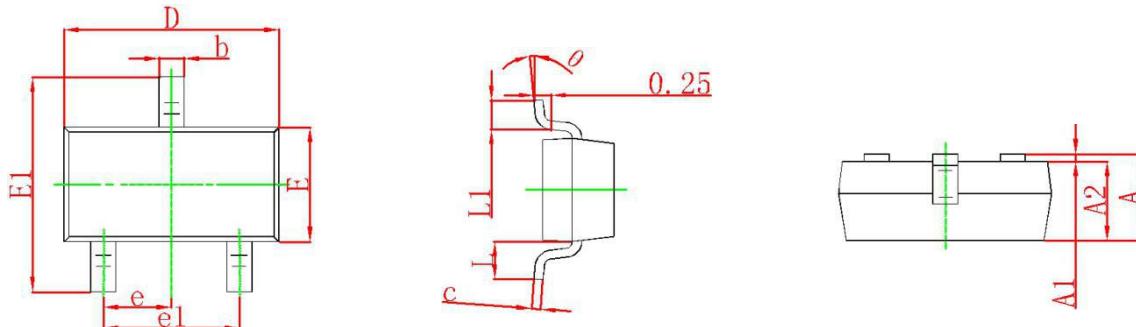
Figure 14 Normalized Maximum Transient Thermal Impedance



SOT-23 Plastic-Encapsulate MOSFETS

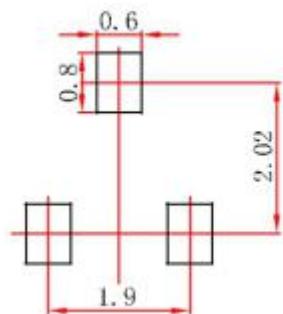
TF2301A

SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.